

## Arkansas Power Electronics International, Inc. High Temperature and High Power Density SiC Power Electronic Converters

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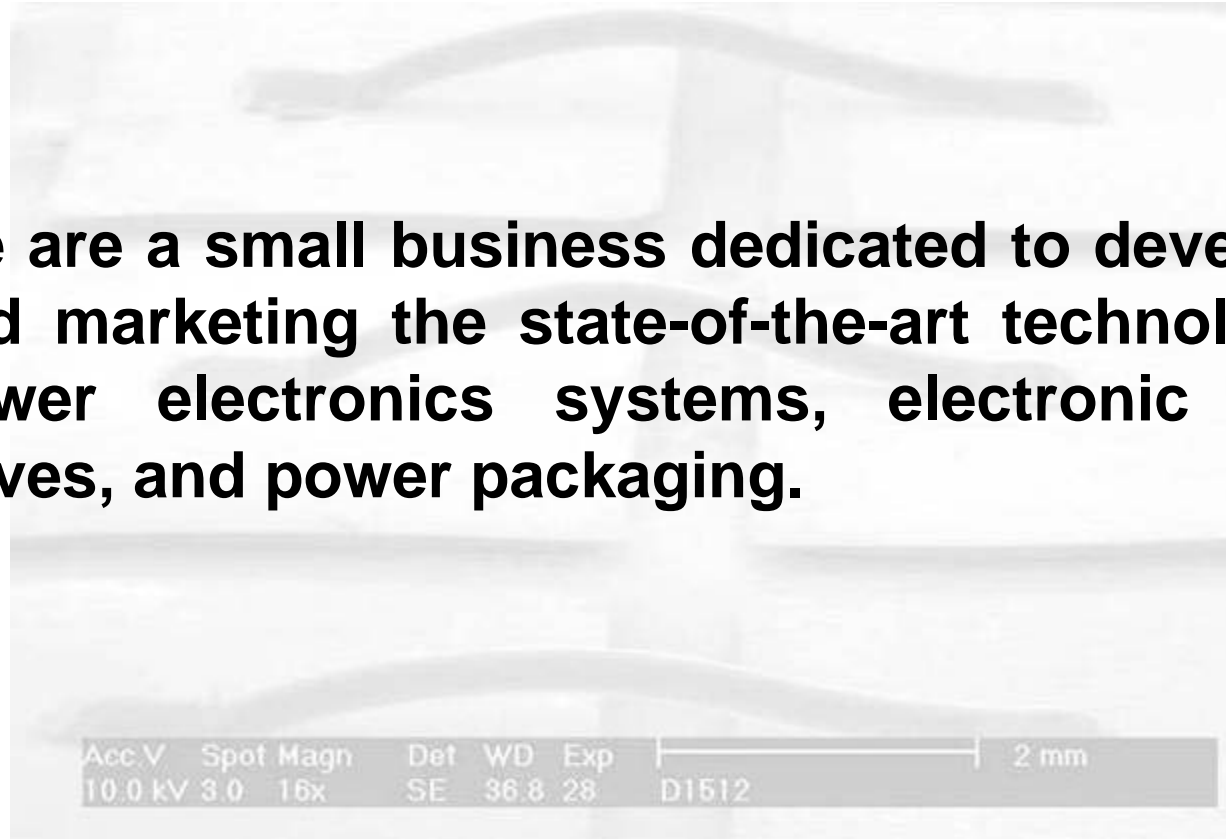
Website: [www.apei.net](http://www.apei.net)

## Overview

- **APEI, Inc. Corporate Status**
- **Broader Impact of SiC-based Power Converter**
- **DOE Energy Storage System Program Phase I SBIR**
  - SBIR Topic: Wide Band Gap Power Converter Application
  - APEI's Goals
  - Phase I Accomplishments
- **DOE Energy Storage System Program Phase II SBIR**
  - APEI's Goals
  - Research Team and Partners
  - Project Status

## APEI, Inc. Mission Statement

**We are a small business dedicated to developing and marketing the state-of-the-art technology in power electronics systems, electronic motor drives, and power packaging.**

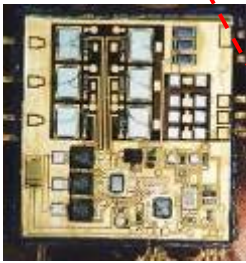


## APEI, Inc. Company Information

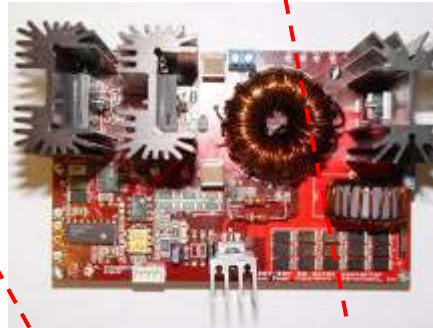
- **Founded in 1997**
  - Original founder, Dr. Kraig Olejniczak left in 2002
  - We shifted emphasis from consulting to R&D product development in 2002
  - Moved out of Genesis in 2006 into the Innovation Center
- **Employees**
  - Have grown from 1 employee in 2002 to the present 19 employees
  - Includes 4 Ph.D.s, 5 M.S., 2 MBA, 4 BS, 4 Interns
- **Revenues**
  - Have grown from \$14k in revenues in 2002 to the present \$2+ million annually
  - \$2 million in contracts secured for 2007 with projections to exceed \$3 million
  - Revenues approximately 50/50 split between Federal and commercial R&D contracts
  - APEI, Inc. will release first “engineering sample” products in 2007
- **Facilities**
  - Have grown from 100 sq. ft. in 2002 to the present ~6,000 sq. ft. including 2 clean rooms and 2 test laboratories
- **Intellectual Property**
  - 1 patent has been awarded
  - ~ 6 patents are under filing and review
  - Trade secrets
  - ~ 150 international publications by company employees

## APEI, Inc. Technology

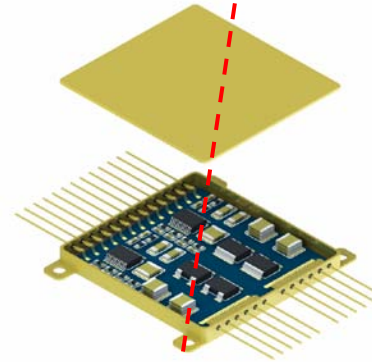
Multichip Power Modules (MCPMs)



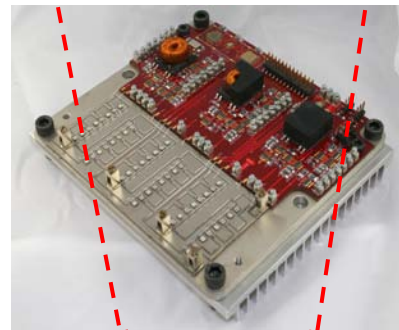
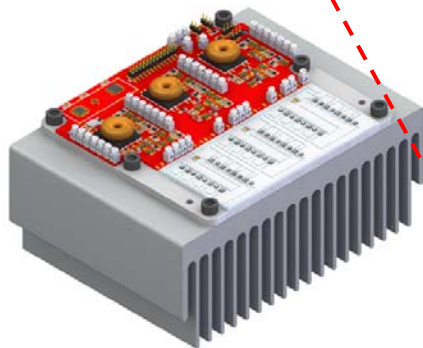
High Temperature Testing & Design



High Temperature Power Packaging



Silicon Carbide Electronics



High Density Power Electronics

\* Note: Semisouth LTSIT

## Applications for SiC-based Power Converters

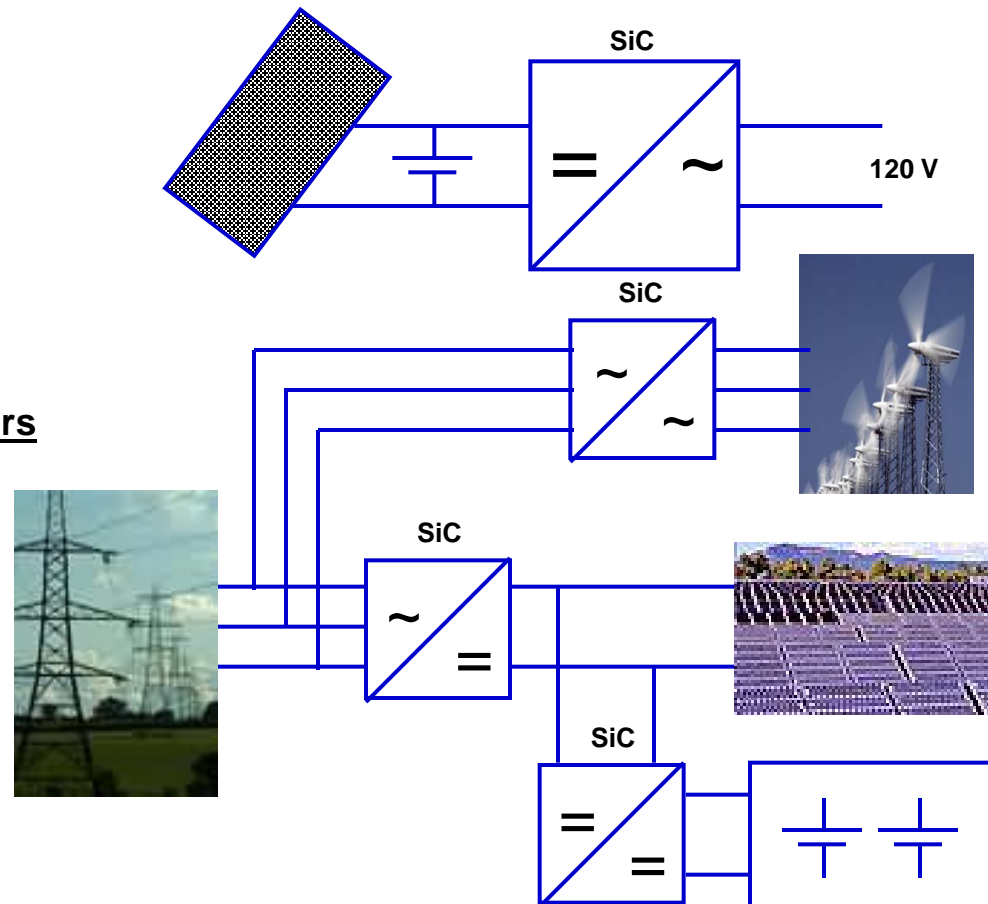
**FY05 SBIR Topic:** Wide Band Gap Power Converter Application

### Single-Phase Inverter

- ➔ 3 kW proof-of-concept prototype
- ➔ Stand-alone application

### Three-Phase Inverters and DC/DC Converters

- ➔ High-power applications
- ➔ Renewable energy sources



## The Advantages of Silicon Carbide

### Thermal Advantages

- SiC device theoretical limit exceeds 600 °C  
**Very high power densities can be achieved with these junction temperatures.**
- SiC has a very high thermal conductivity— excellent for power devices and thermal transfer, increases power density
- **Disadvantage:** currently no device packaging technology exists to take full advantage of thermal capabilities.  
**Requires packaging advances in die attach, interconnects, and reliability.**

### Electrical Advantages

- Very low switching losses (1/10<sup>th</sup> of Si) w/ smaller drive currents and smaller on-resistances
- Up to 10s to 100s of GHz switching range
- Very high voltage blocking

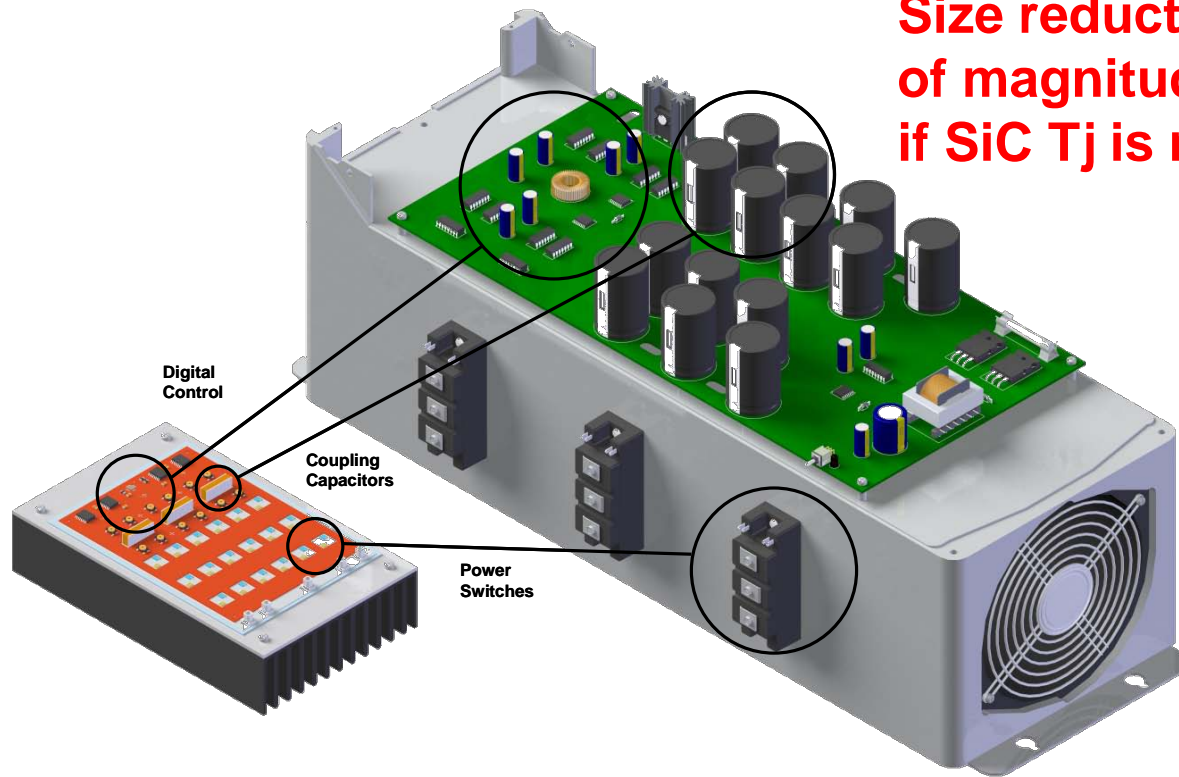
## DOE ESS Phase I SBIR Review

- **Phase I SBIR (FY05)**
  - **Partnership between APEI, Inc and GeneSiC**
  - **Goal: Demonstrate the advantages of a SiC-based power converter as interface for advanced energy storage systems**
  - **Technology Demonstrator: 3-kW 120V single-phase inverter capable of operating at high-temperature (250 °C+)**



## Potential Size Reduction Using SiC

Size reduction of an order of magnitude achievable if SiC  $T_j$  is maximized

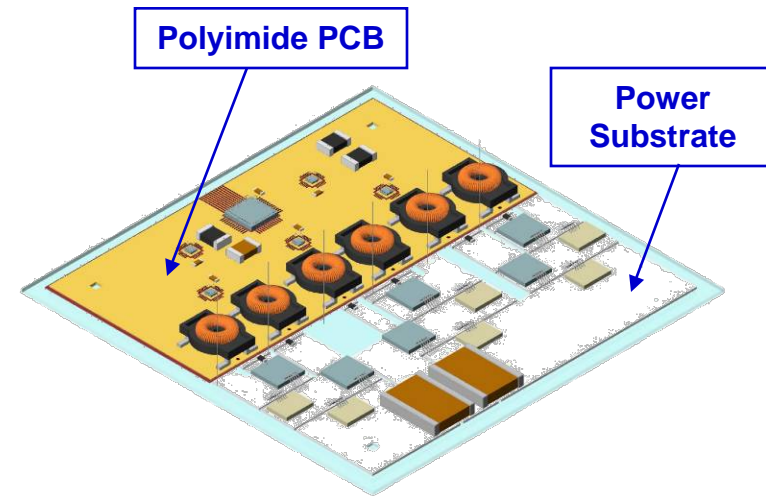
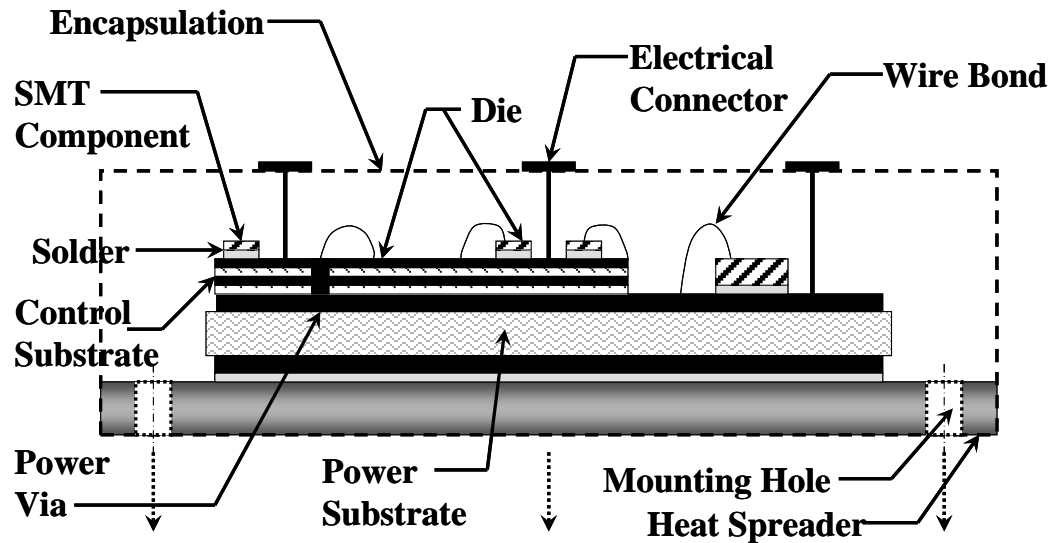


30 kW APEI SiC Power Module

30 kW Standard Power Module

## MCPM Packaging Approach

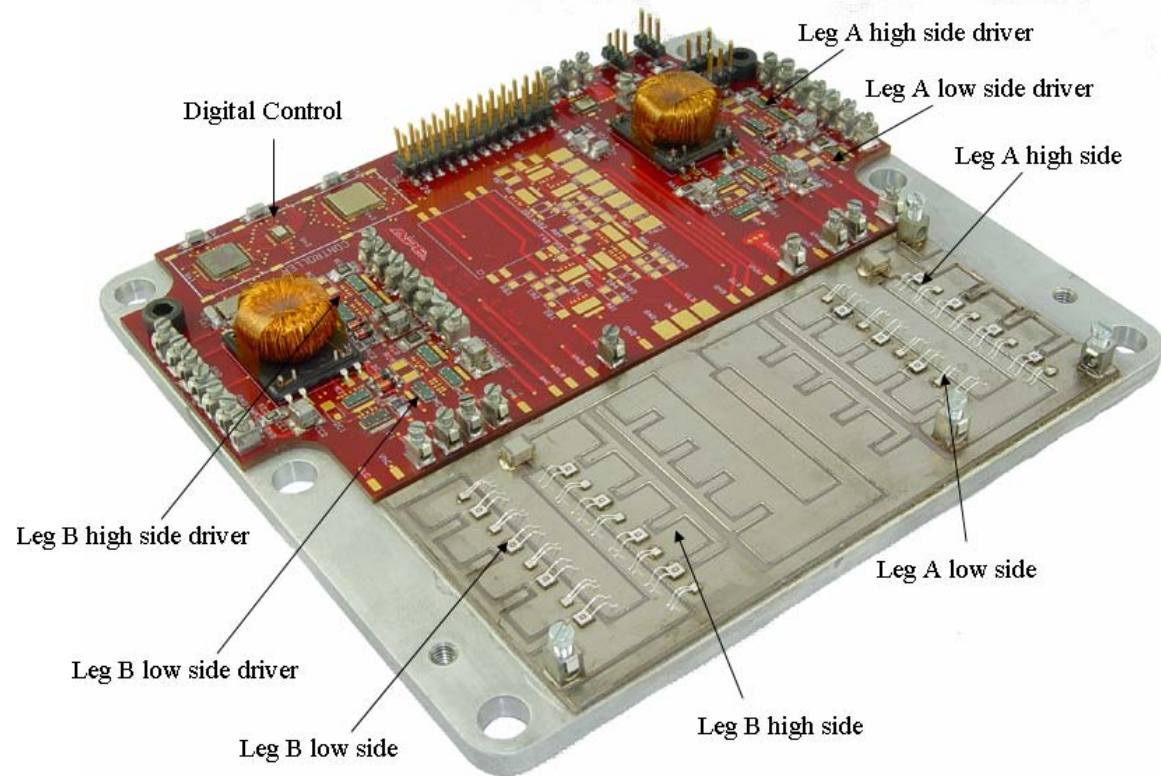
Cross-section of the SiC MCPM design (\*)    Isometric view of high-temperature MCPM



(\*) APEI, Inc. patented technology

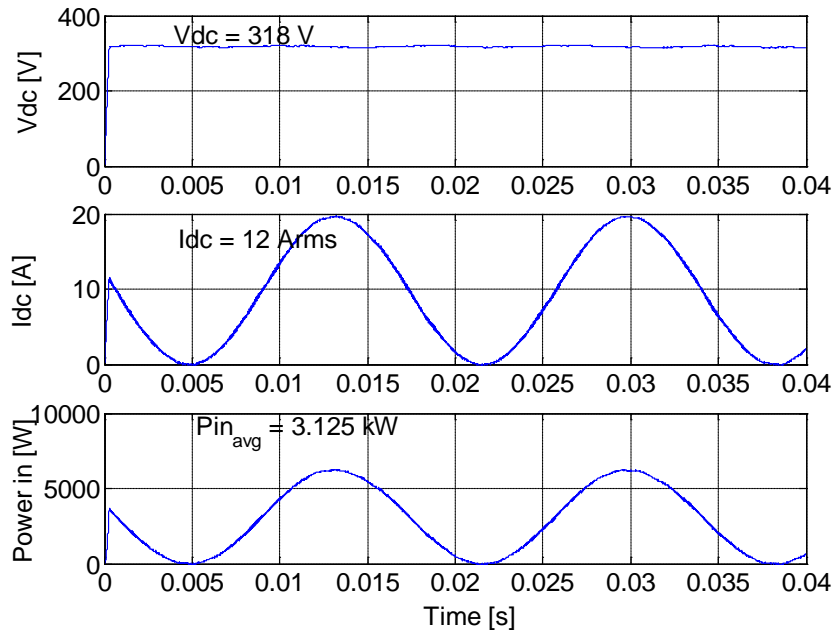
## DOE ESS Phase I SBIR Review

- **Technology Demonstrator**
  - **3-kW 120V single-phase inverter (250 °C+)**

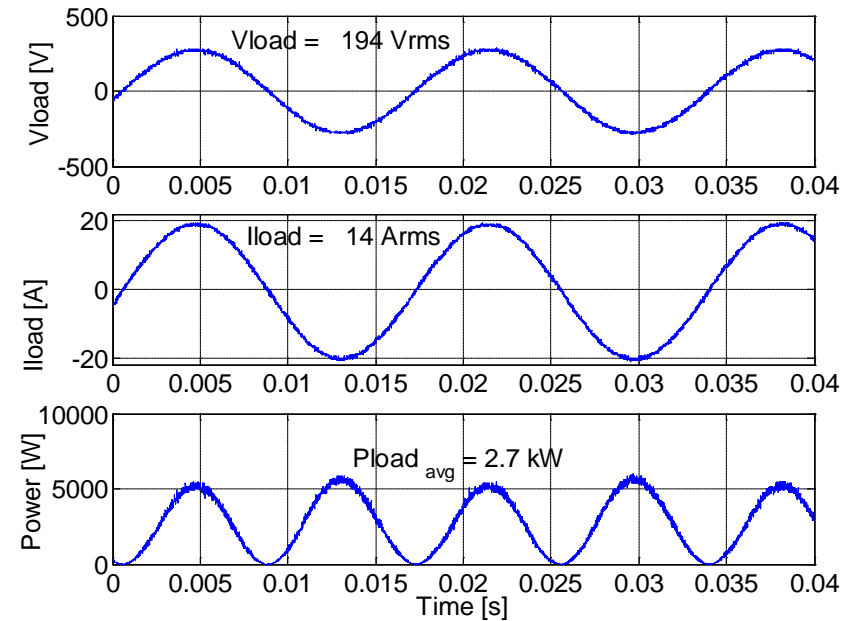


## DOE ESS Phase I SBIR Review

### Input Power



### Output Power



Operation at ~ 3 kW

>90% efficiency

## DOE ESS Phase I SBIR Review



APEI, Inc.'s SiC-based MCPM power inverter module has a power density of 11 W/in<sup>3</sup> (using only passive cooling). This is an 85% volume reduction over current commercial Si-based power inverters.

\*Note: this portion of the Si inverter was **not** included in the calculations.

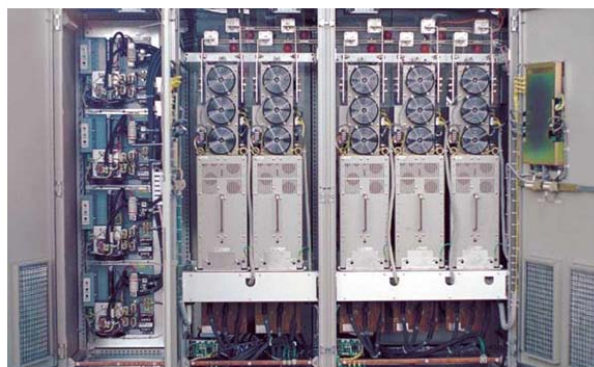
## DOE ESS Phase II SBIR

- **Phase II SBIR (FY06)**
  - Phase II started on August 2006
  - **Goal:** In Phase II, APEI, Inc. will take the concepts demonstrated in Phase I and develop a fully-functional multi-purpose 100 kW SiC-based DC/AC power converter prototype with 75%+ volume reduction over silicon equivalent systems.
  - **Industry and Governmental Support:**
    - State of Arkansas
    - Baldor Motors and Drives
    - Northrop Grumman
    - National Center for Reliable Electric Power Transmission (NCREPT)

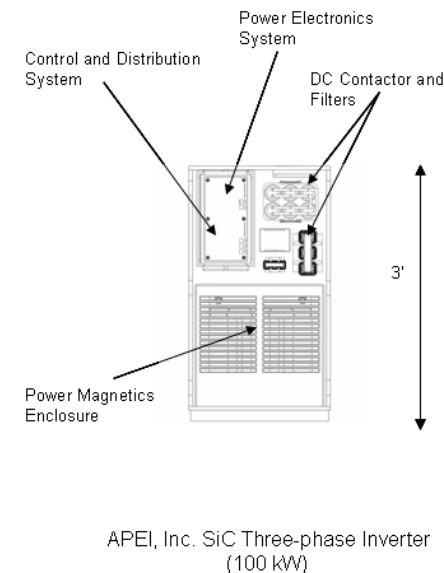
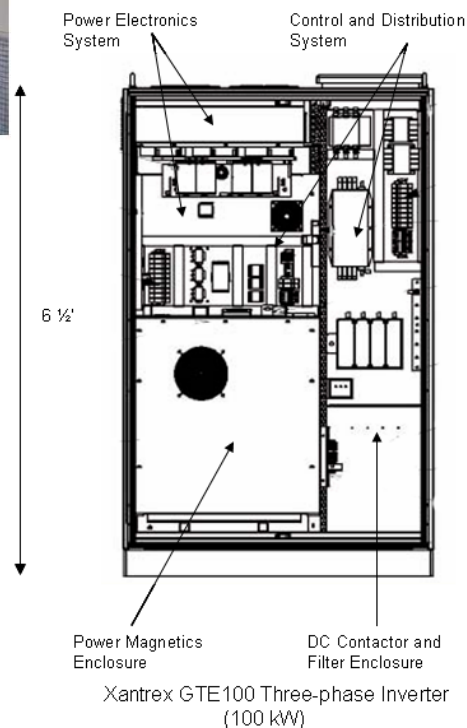
## DOE ESS Phase II SBIR



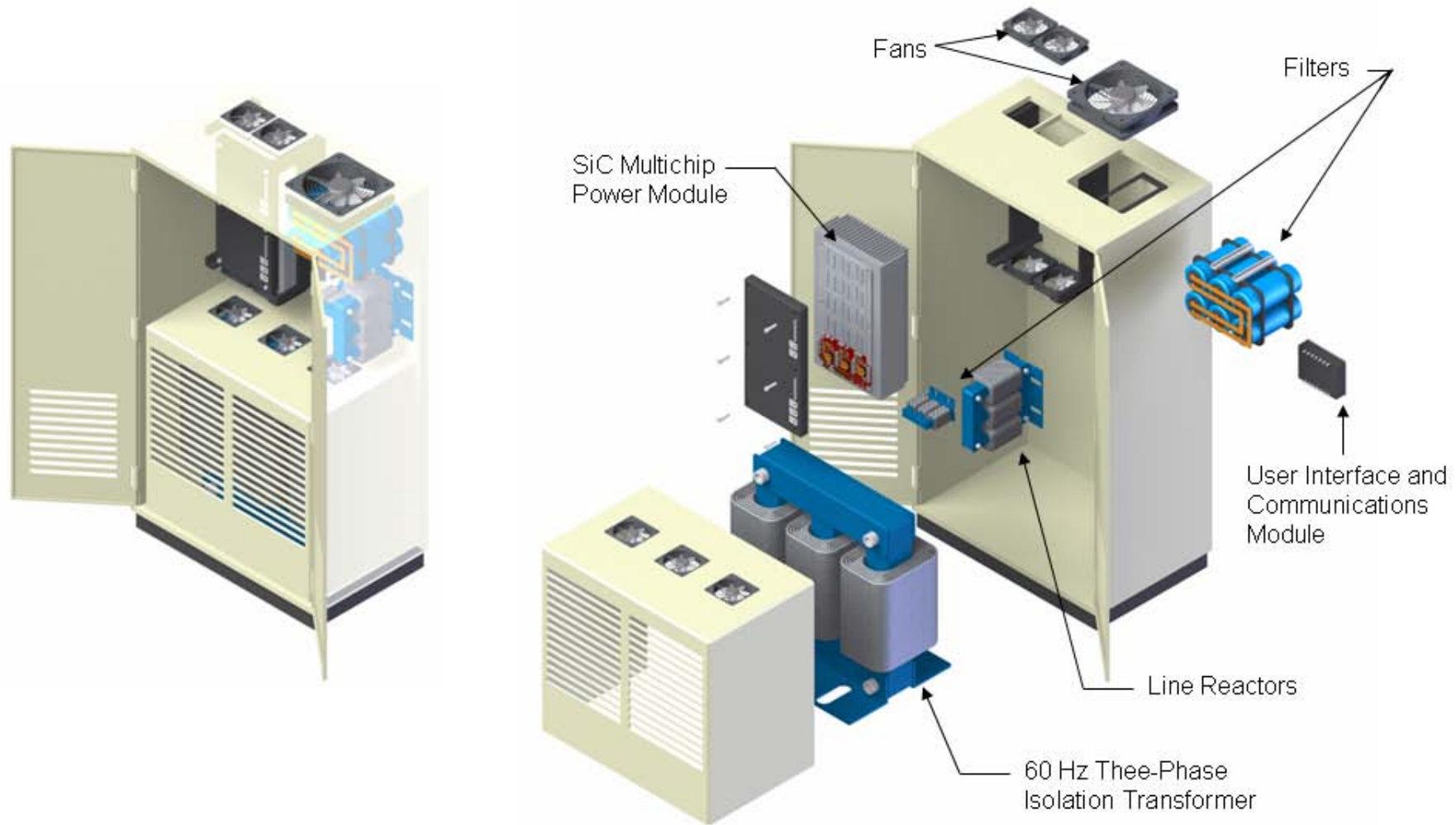
Commercial Si based Photo-Voltaic Grid Tie Three-Phase Inverter (100 kW)



Commercial Si Based Three-Phase Motor Drive (400 kW)



## DOE ESS Phase II SBIR



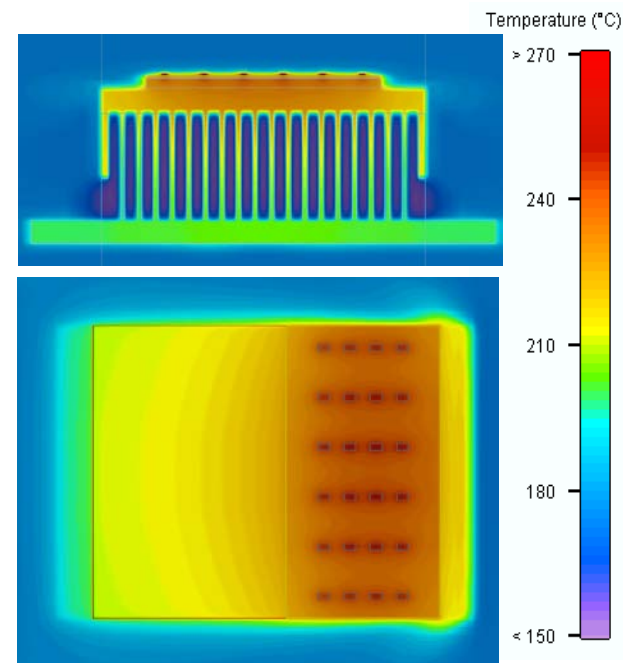
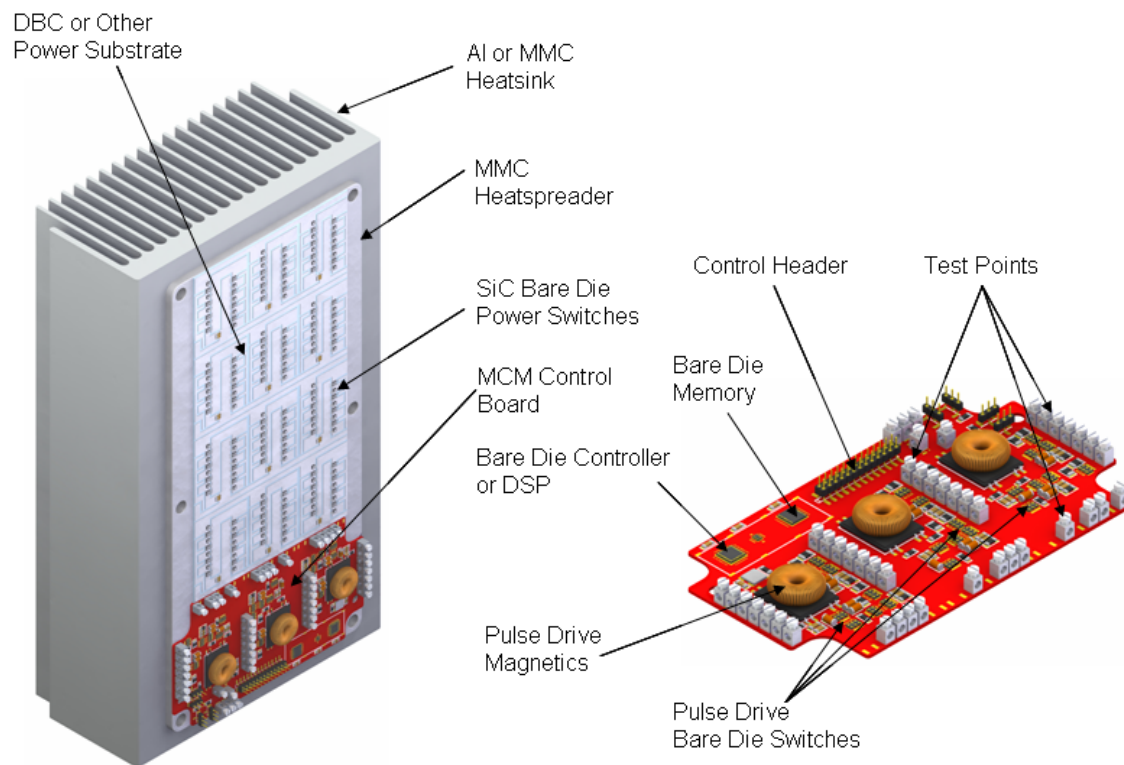


## DOE ESS Phase II SBIR

- **Phase II SBIR Tasks/Current Status**
  - **Task One: Overall Mechanical Design and Layout (Started)**
  - **Task Two: SiC Multichip Power Module Packaging (Started)**
  - **Task Three: Electric Design of a Switch Position (Started)**
  - **Task Four: Electrical Design of the Power Stage**
  - **Task Five: Electrical Design of the Control Stage**
  - **Task Six: SiC JFET Fault Limiter (GeneSiC)**
  - **Task Seven: SiC Inverter Fabrication and Testing**

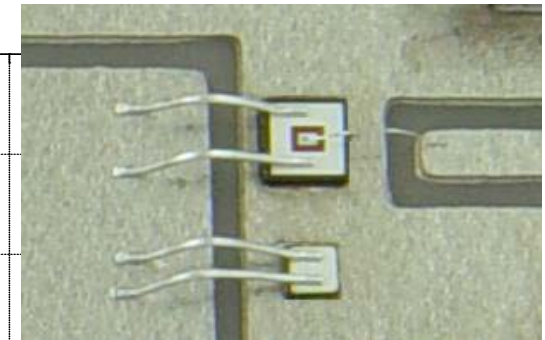
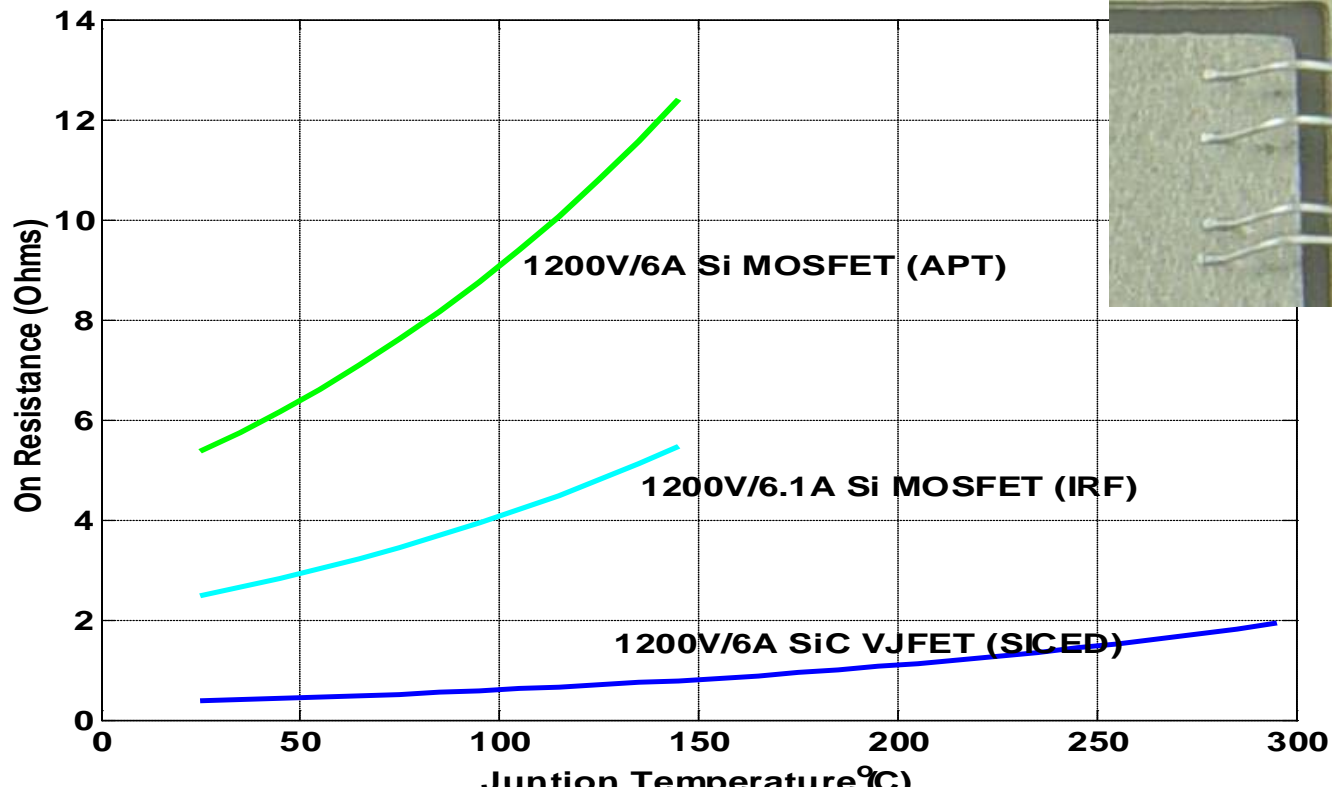
## DOE ESS Phase II SBIR

### SiC MCPM Mechanical and Thermal Design



## DOE ESS Phase II SBIR

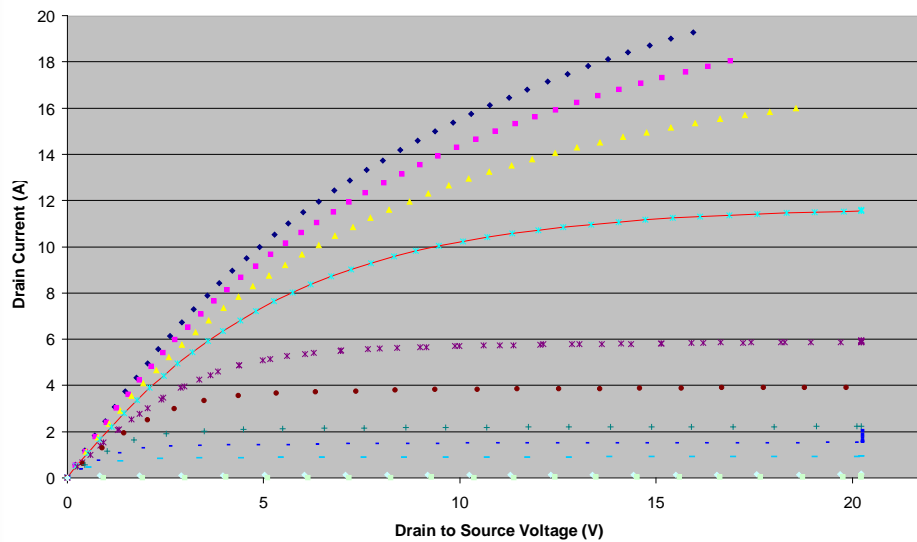
### Electrical Design of SiC Switch Position



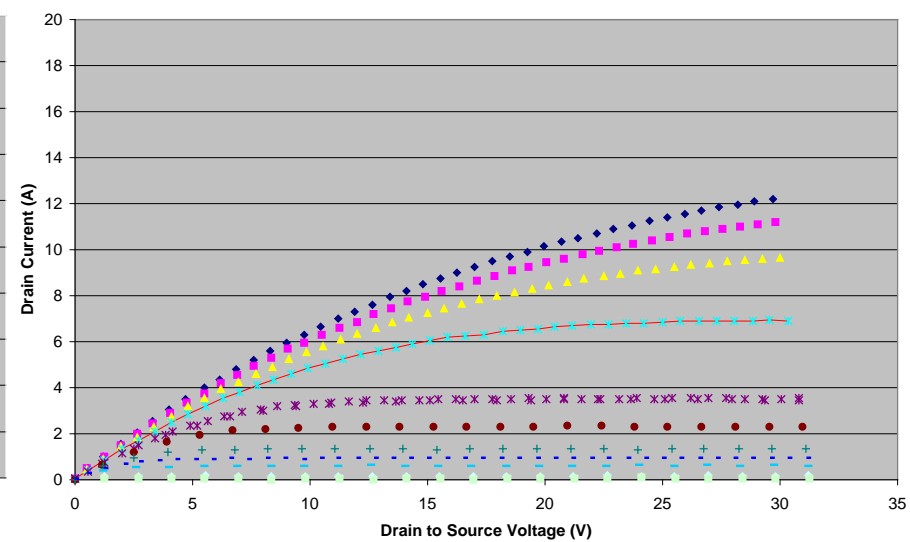
## DOE ESS Phase II SBIR

### Electrical Design of SiC Switch Position - Characterization of devices over temperature

On State Curves- Board B at 20°C



On State Curves- Board B at 250°C



## Summary

- **SiC has the potential of greatly increase the performance power converters enabling distributed generation**
  - Higher efficiency
  - Smaller size
  - Higher reliability
  - And ultimate lower cost
- **Phase I work focused on prove-of-concept**
  - 3-kW/120V single-phase inverter
  - Great volume reduction
  - Demonstrate high-temperature operation (250 °C)
- **Phase II work focus on higher power level and high integration of complete system**
  - 100 kW 3-phase inverter
  - 75%+ volume reduction of complete system

## DOE ESS Phase II SBIR

### • Phase II SBIR Future Work

- **Task Two: SiC Multichip Power Module Packaging**
  - Thermal analysis based on switch position loss estimation (Task Three)
  - Optimization of temperature rise vs. losses
  - Thermal-stress analysis based on maximum temperature rise
- **Task Three: Electric Design of a Switch Position (Started)**
  - Final selection and characterization of power devices (VJFET/Diode)
  - Optimization of “device paralleling”
- **Task Four: Electrical Design of the Power Stage**
  - Begin the selection/sizing of DC link capacitors and output/input filters
- **Task Five: Electrical Design of the Control Stage**
  - Design of gate drive circuitry
  - Begin the development of the digital controller

## Acknowledgments

- **Department of Energy (DOE)**
  - Energy Storage System Program, directed by Dr. Imre Gyuk
  - Sandia National Labs, Stan Atcitty
- **APEI's Partners**
  - GeneSiC
  - State of Arkansas
  - Northrop Grumman Advanced Technology Center
  - Baldor Motors and Drives